

H11L1M, H11L2M, H11L3M 6-Pin DIP Optocoupler

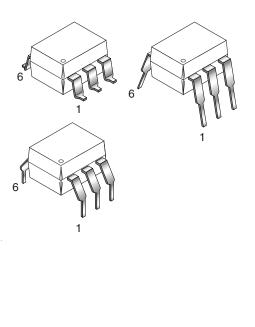
Features

- High data rate, 1MHz typical (NRZ)
- Free from latch up and oscilliation throughout voltage and temperature ranges.
- Microprocessor compatible drive
- Logic compatible output sinks 16mA at 0.4V maximum
- Guaranteed on/off threshold hysteresis
- Wide supply voltage capability, compatible with all popular logic systems
- Underwriters Laboratory (UL) recognized file #E90700, Volume 2
- VDE recognized File#102497 Add option V (e.g., H11LIVM)

Applications

- Logic to logic isolator
- Programmable current level sensor
- Line receiver—eliminate noise and transient problems
- A.C. to TTL conversion—square wave shaping
- Digital programming of power supplies
- Interfaces computers with peripherals

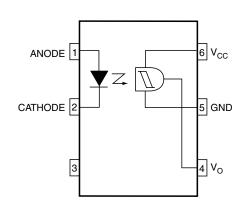
Packages



Description

The H11LXM series has a high speed integrated circuit detector optically coupled to a gallium-arsenide infrared emitting diode. The output incorporates a Schmitt trigger, which provides hysteresis for noise immunity and pulse shaping. The detector circuit is optimized for simplicity of operation and utilizes an open collector output for maximum application flexibility.

Schematic



Truth Table

Input	Output
Н	L
L	Н

Symbol	Parameters	Value	Units
TOTAL DEVICE			
T _{STG}	Storage Temperature	-55 to +150	°C
T _{OPR}	Operating Temperature	-40 to +85	°C
T _{SOL}	Lead Solder Temperature	260 for 10 sec	°C
P _D	Total Device Power Dissipation @ 25°C	250	mW
	Derate Above 25°C	2.94	mW/°C
EMITTER			
١ _F	Continuous Forward Current	60	mA
V _R Reverse Voltage		6	V
I _F (pk) Forward Current – Peak (1µs pulse, 300pps)		3.0	А
P _D	LED Power Dissipation 25°C Ambient	120	mW
	Derate Linearly From 25°C	1.41	mW/°C
DETECTOR			
PD	Detector Power Dissipation @ 25°C	150	mW
	Derate Linearly from 25°C	2.0	mW/°C
V _O	V ₄₅ Allowed Range	0 to 16	V
V _{CC}	V ₆₅ Allowed Range	3 to 16	V
Ι _Ο	I ₄ Output Current	50	mA

Electrical Characteristics ($T_A = 25^{\circ}C$ Unless otherwise specified.) Individual Component Characteristics

Symbol	Parameters	Test Conditions	Device	Min.	Тур.	Max.	Units
EMITTER							
V _F	Input Forward Voltage	I _F = 10mA	All		1.2	1.5	V
		I _F = 0.3mA		0.75	1.0		
I _R	Reverse Current	V _R = 3V	All			10	μA
CJ	Capacitance	V = 0, f = 1.0MHz	All			100	pF
DETECTOR	2	•	•		•		
V _{CC}	Operating Voltage Range		All	3		15	V
I _{CC(off)}	Supply Current	$I_{\rm F} = 0, V_{\rm CC} = 5V$	All		1.6	5.0	mA
I _{OH}	Output Current, High	$I_{\rm F} = 0, V_{\rm CC} = V_{\rm O} = 15V$	All			100	μA

Transfer Characteristics

Symbol	Parameter	Test Conditions	Device	Min.	Тур.	Max.	Units
DC CHARA	CTERISTICS		1		1	1	
I _{CC(on)}	Supply Current	I _F = 10mA, V _{CC} = 5V	All		1.6	5.0	mA
V _{OL}	Output Voltage, low	$\begin{array}{ll} R_{L} = & 270\Omega, V_{CC} = 5V, \\ I_{F} = & I_{F(on)} \mbox{ max}. \end{array}$	All		0.2	0.4	V
I _{F(on)}	Turn-On Threshold Current ⁽¹⁾	$R_L = 270\Omega, V_{CC} = 5V$	H11L1M			1.6	mA
			H11L2M			10.0	
			H11L3M			5.0	
I _{F(off)}	Turn-Off Threshold Current	$R_L = 270\Omega, V_{CC} = 5V$	All	0.3	1.0		mA
I _{F(off)} /I _{F(on)}	Hysteresis Ratio	$R_L = 270\Omega, V_{CC} = 5V$	All	0.50	0.75	0.90	
AC CHARA	CTERISTICS, Switching Speed	b					
t _{on}	Turn-On time	$ \begin{array}{l} R_{L} = 270\Omega, V_{CC} = 5V, \\ I_{F} = I_{F(on)}, T_{A} = 25^{\circ}C \end{array} $	All		1.0	4	μs
t _f	Fall Time		All		0.1		μs
t _{off}	Turn-Off Time	$ \begin{array}{l} R_{L} = 270\Omega, V_{CC} = 5V, \\ I_{F} = I_{F(on)}, T_{A} = \ 25^{\circ}C \end{array} $	All		1.2	4	μs
t _r	Rise time	$\label{eq:RL} \begin{split} R_L &= 270\Omega, V_{CC} = 5V, \\ I_F &= I_{F(on)}, T_A = 25^\circ C \end{split}$	All		0.1		μs
	Data Rate		All		1.0		MHz
	1	1	-				

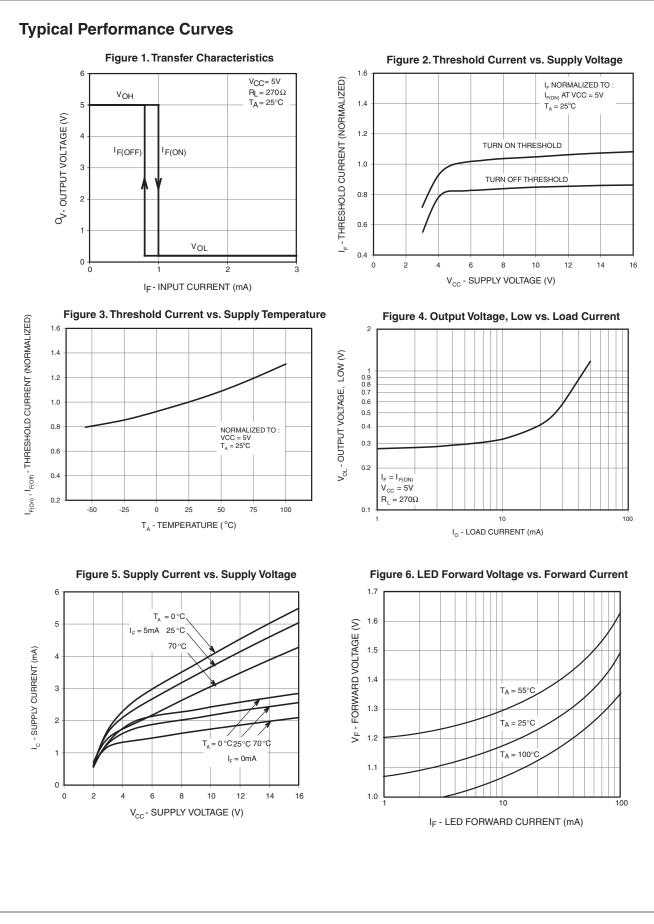
Isolation Characteristics

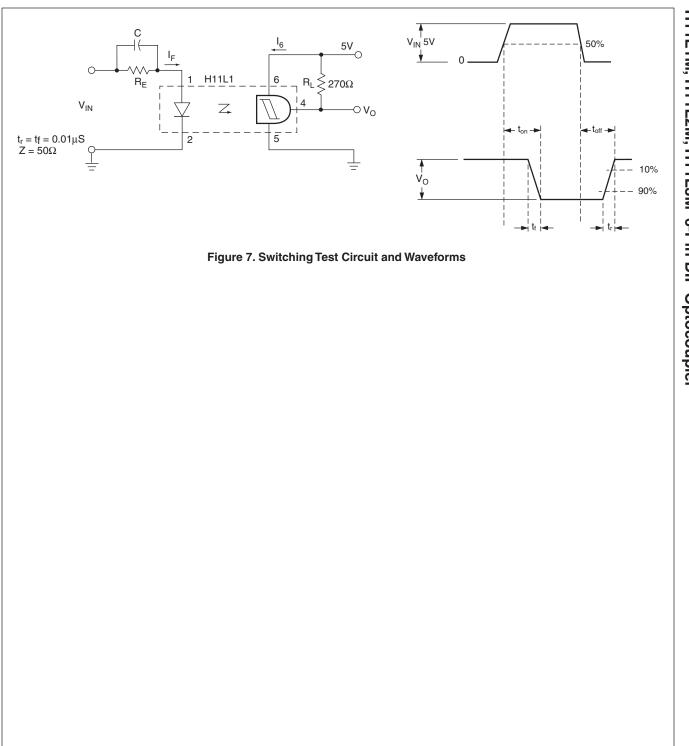
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
V _{ISO}	Input-Output Isolation Voltage	t =1 sec.	7500			V _{PEAK}
C _{ISO}	Isolation Capacitance	$V_{I-O} = 0V$, f = 1MHz		0.4	0.6	pF
R _{ISO}	Isolation Resistance	$V_{I-O} = \pm 500 \text{ VDC}$	10 ¹¹			Ω

Note:

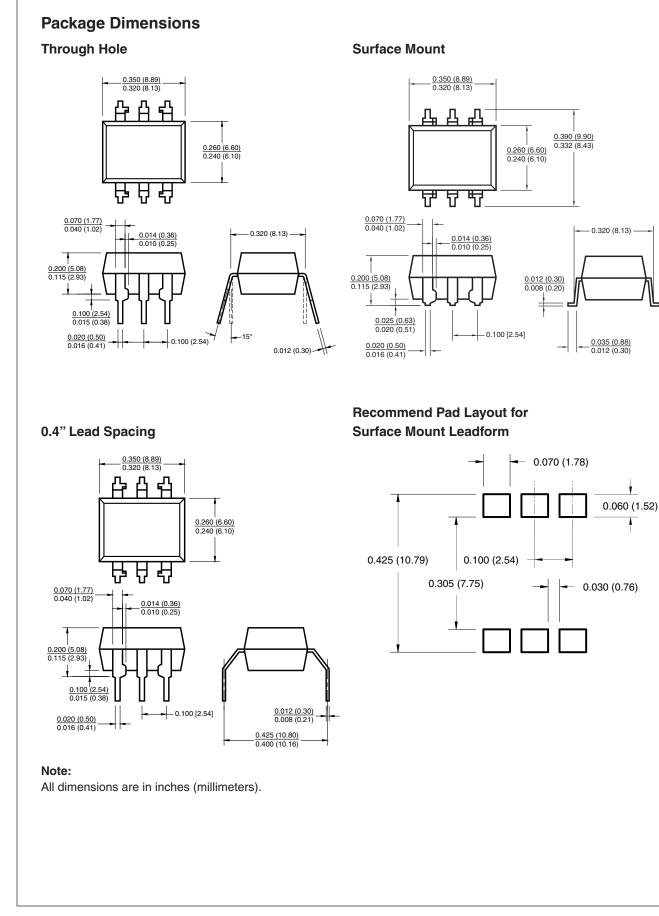
 Maximum I_{F(ON)} is the maximum current required to trigger the output. For example, a 1.6mA maximum trigger current would require the LED to be driven at a current greater than 1.6mA to guarantee the device will turn on. A 10% guard band is recommended to account for degradation of the LED over its lifetime. The maximum allowable LED drive current is 60mA.

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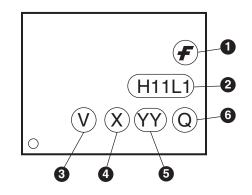


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Ordering Information

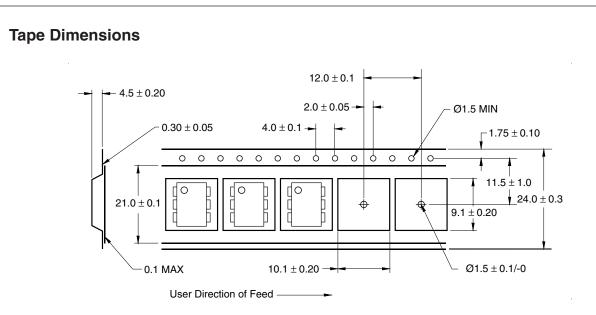
Option/Order Entry Identifier	Description
S	Surface Mount Lead Bend
SR2	Surface Mount; Tape and reel
Т	0.4" Lead Spacing
V	VDE 0884
TV	VDE 0884, 0.4" Lead Spacing
SV	VDE 0884, Surface Mount
SR2V	VDE 0884, Surface Mount, Tape & Reel

Marking Information



Definit	ions			
1	1 Fairchild logo			
2	evice number			
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)			
4	ne digit year code, e.g., '3'			
5	Two digit work week ranging from '01' to '53'			
6	Assembly package code			

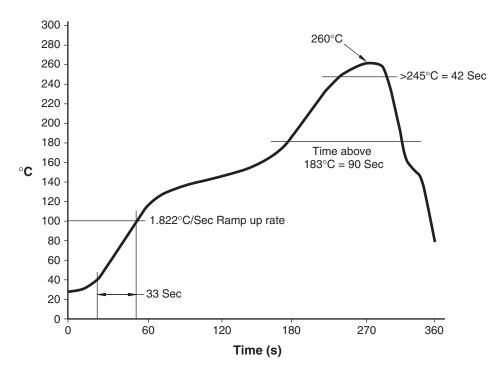
*Note – Parts that do not have the 'V' option (see definition 3 above) that are marked with date code '325' or earlier are marked in portrait format.



Note:

All dimensions are in millimeters.

Reflow Profile





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CROSSVOLT™	<i>i-Lo</i> ™	POP™	SuperSOT™-3	
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FAST®	MicroFET™	QS™	TinyBuck™	
FASTr™	MicroPak™	QT Optoelectronics [™]	TinyPWM™	
FPS™	MICROWIRE™	Quiet Series™	TinyPower™	
FRFET™	MSX™	RapidConfigure™	TinyLogic [®]	
	MSXPro™	RapidConnect™	TINYOPTO™	
Across the board. A	-	µSerDes™	TruTranslation™	
The Power Franchis	se [®]	ScalarPump™	UHC [®]	
Programmable Activ	o Droop™			

Programmable Active Droop™

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